



DMG6898LSD

DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Up To 2kV
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

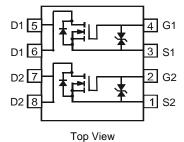
Mechanical Data

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Weight: 0.072 grams (approximate)





Top View



Internal Schematic

Ordering Information (Note 3)

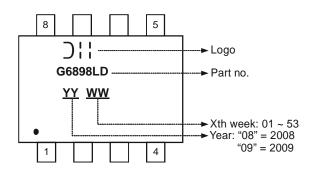
Part Number	Qualification	Case	Packaging
DMG6898LSD-13	Commercial	SO-8	2500 / Tape & Reel
DMG6898LSDQ-13	Automotive	SO-8	2500 / Tape & Reel

Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. No purposely added lead. Halogen and Antimony free.

2. Diodes Inc.'s "Green" Policy can be found on our website at http://www.diodes.com

3. For packaging details, go to our website at http://www.diodes.com.

Marking Information





Maximum Ratings @T_A = 25°C unless otherwise specified

Char	acteristic		Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	20	V
Gate-Source Voltage			V _{GSS}	±12	V
Continuous Drain Current (Note 4)	Steady State	T _A = 25°C T _A = 85°C	ID	9.5 7.1	A
Pulsed Drain Current (Note 5)			I _{DM}	30	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4)	PD	1.28	W
Thermal Resistance, Junction to Ambient $@T_A = 25$ °C (Note 4)	R _{0JA}	99.3	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics @T_A = 25°C unless otherwise specified

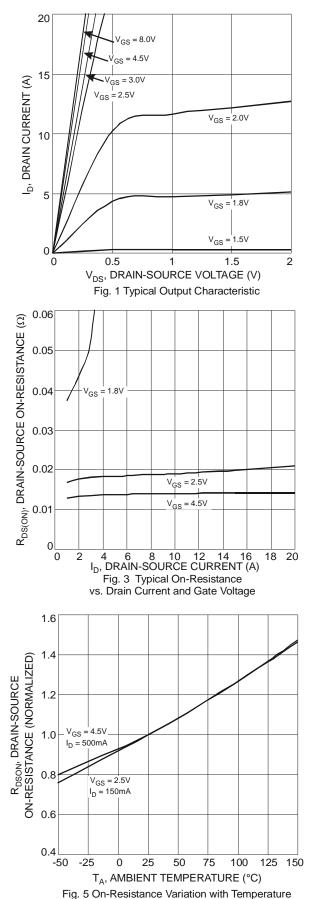
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)						·	
Drain-Source Breakdown Voltage	BV _{DSS}	20	-	-	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current T _J = 25°C	I _{DSS}	-	-	1.0	μA	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	-	-	±10	μA	$V_{GS} = \pm 12V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage	V _{GS(th)}	0.5	1.0	1.5	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	D	-	11 17	16 23	mΩ	$V_{GS} = 4.5V, I_D = 9.4A$	
	R _{DS (ON)}					$V_{GS} = 2.5V, I_D = 8.3A$	
Forward Transfer Admittance	Y _{fs}	-	17	-	S	$V_{DS} = 5V, I_D = 9.4A$	
Diode Forward Voltage	V _{SD}	-	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1.3A$	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	Ciss	-	1149	-	pF		
Output Capacitance	Coss	-	157	-	pF	− V _{DS} = 10V, V _{GS} = 0V, − f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	-	142	-	pF		
Gate Resistance	R _g	-	1.51	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	-	11.6	-	nC		
Total Gate Charge (V _{GS} = 10V)	Qg	-	26	-	nC	V _{GS} = 4.5V, V _{DS} = 10V,	
Gate-Source Charge	Q _{gs}	-	2.7	-	nC	I _D = 9.4A	
Gate-Drain Charge	Q _{gd}	-	3.4	-	nC		
Turn-On Delay Time	t _{D(on)}	-	11.67	-	ns		
Turn-On Rise Time	tr	-	12.49	-	ns	$V_{DD} = 10V, V_{GS} = 4.5V,$	
Turn-Off Delay Time	t _{D(off)}	-	35.89	-	ns	$R_{GEN} = 6\Omega, I_D = 1A$	
Turn-Off Fall Time	t _f	-	12.33	-	ns		

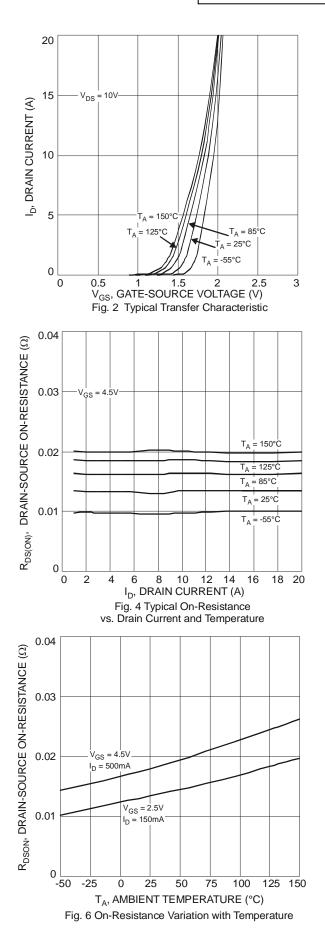
Notes:

Device mounted on FR-4 PCB, with minimum recommended pad layout.
Repetitive rating, pulse width limited by junction temperature.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing.

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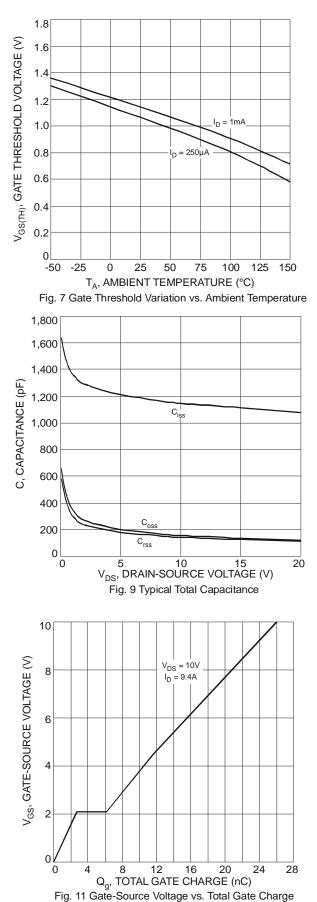


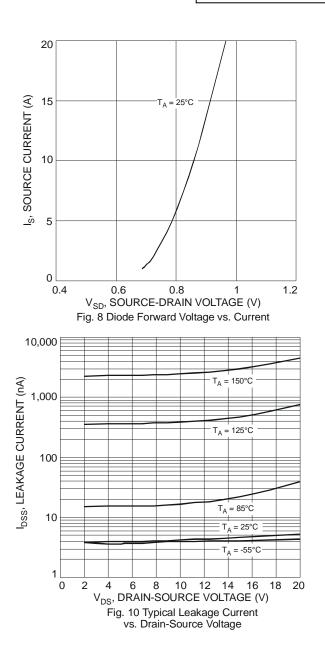


DMG6898LSD Document number: DS31947 Rev. 4 - 2

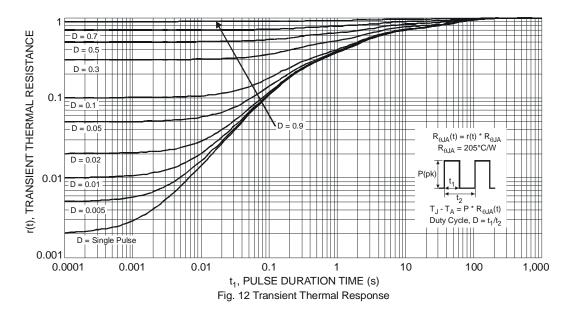
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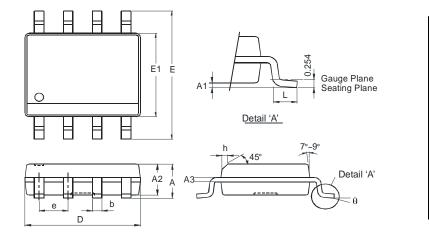






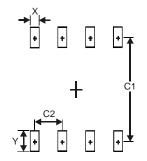


Package Outline Dimensions



SO-8					
Dim	Min	Max			
Α	-	1.75			
A1	0.10	0.20			
A2	1.30	1.50			
A3	0.15	0.25			
b	0.3	0.5			
D	4.85	4.95			
Е	5.90	6.10			
E1	3.85	3.95			
e	1.27 Typ				
h	-	0.35			
L	0.62	0.82			
θ	0°	8°			
All Dimensions in mm					

Suggested Pad Layout



Dimensions	Value (in mm)
Х	0.60
Y	1.55
C1	5.4
C2	1.27



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